# SKiiP 1602GB061-459CTV ...

**Power section** 

Features

intelligent Power System

SKiiP 1602GB061-459CTV

SKiiP technology inside

Integrated current sensor

Integrated heat sink

Integrated temperature sensor

IEC 60721-3-3 (humidity) class

3K3/IE32 (SKiiP<sup>®</sup> 2 System)

(SKiiP<sup>®</sup> 2 power section)

per terminal (SEMIKRON type is

8) AC connection busbars must be

recommended)

available on request

IEC 68T.1 (climate) 40/125/56

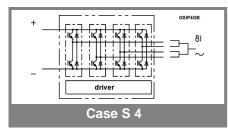
1) with assembly of suitable MKP capacitor

connected by the user; copper busbars

Low loss IGBTs CAL diode technology

	Absolut	e Maximum Ratings	$T_s$ = 25 °C unless otherwise specified				
	Symbol	Conditions	Values	Units			
	IGBT	IGBT					
	V <sub>CES</sub>		600	V			
	V <sub>CES</sub> V <sub>CC</sub> <sup>1)</sup>	Operating DC link voltage	400	V			
	V <sub>GES</sub>		± 20	V			
	Ι <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1600 (1200)	А			
	Inverse	Inverse diode					
	I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1600 (1200)	Α			
SKiiP <sup>®</sup> 2	I <sub>FSM</sub>	T <sub>i</sub> = 150 °C, t <sub>p</sub> = 10 ms; sin.	16000	Α			
SKIIP <sup>®</sup> 2	I²t (Diode)	Diode, $T_j = 150 \text{ °C}$ , 10 ms	1280	kA²s			
	T <sub>j</sub> , (T <sub>stg</sub> )		- 40 (- 25) + 150 (125)	°C			
2-pack - integrated	V <sub>isol</sub>	AC, 1 min. (mainterminals to heat sink)	2500	V			

#### T<sub>s</sub> = 25 °C unless otherwise specified Characteristics Symbol |Conditions min. max. Units typ. IGBT V<sub>CEsat</sub> I<sub>C</sub> = 1600 A, T<sub>i</sub> = 25 (125) °C 2,3 (2,6) 2,6 V $V_{\rm CEO}$ $T_i = 25 (125) \circ C$ 0,8 (0,7) 1 (0,9) V T<sub>i</sub> = 25 (125) °C 0,9 (1,2) 1 (1,3) mΩ r<sub>CE</sub> $V_{GE} = 0 V, V_{CE} = V_{CES},$ (80) 1,6 mΑ I<sub>CES</sub> T<sub>i</sub> = 25 (125) °C Eon + Eoff $I_{\rm C}$ = 1600 A, $V_{\rm CC}$ = 300 V 144 mJ T<sub>i</sub> = 125 °C, V<sub>CC</sub> = 400 V 211 mJ R<sub>CC' + EE'</sub> terminal chip, T<sub>i</sub> = 125 °C 0,13 mΩ top, bottom 3,8 nH L<sub>CE</sub> C<sub>CHC</sub> per phase, AC-side 3.2 nF **Inverse diode** I<sub>F</sub> = 1600 A, T<sub>i</sub> = 25 (125) °C $V_F = V_{EC}$ 1,5 (1,5) 1,8 ٧ T<sub>i</sub> = 25 (125) °C 0,8 (0,6) 1 (0,8) V V<sub>TO</sub> T<sub>i</sub> = 25 (125) °C 0,4 (0,5) 0,5 (0,6) mΩ r<sub>T</sub> $I_{\rm C}$ = 1600 A, $V_{\rm CC}$ = 300 V Err 51 mJ $T_i = 125 \text{ °C}, V_{CC} = 400 \text{ V}$ 61 mJ Mechanical data $M_{dc}$ DC terminals, SI Units 6 8 Nm $M_{ac}$ AC terminals, SI Units 13 15 Nm SKiiP® 2 System w/o heat sink 3,5 w kg 8,5 w heat sink kg Thermal characteristics (P 16 heat sink; 275 m<sup>3</sup>/h); ", "reference to temperature sensor per IGBT 0,028 K/W R<sub>th(j-s)I</sub> per diode 0,05 K/W R<sub>th(j-s)D</sub> per module 0.033 K/W R<sub>th(s-a)</sub> Z<sub>th</sub> R<sub>i</sub> (mK/W) (max. values) tau<sub>i</sub>(s) 2 1 2 3 4 1 3 4 3 21 3 1 0,13 0,001 Z<sub>th(j-r)I</sub> Z<sub>th(j-r)D</sub> 6 39 6 0,13 0,001 1 1,6 22 7 2,4 494 165 20 0.03 Z<sub>th(r-a)</sub>



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# SKiiP 1602GB061-459CTV ...

	Absolute Maxin	
	Symbol	Condi
	V <sub>S1</sub> V <sub>S2</sub>	stabilize unstabil
	V <sub>iH</sub>	input sig
	dv/dt	seconda
	V <sub>isollO</sub>	input / o
	V <sub>isol12</sub>	output 1
	f <sub>max</sub>	switchin
SKiiP <sup>®</sup> 2	$T_{op} (T_{stg})$	operatin

### 2-pack - integrated intelligent Power System

2-pack integrated gate driver

SKiiP 1602GB061-459CTV

#### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)Power supply protected against
- under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP<sup>®</sup> 2 gate driver)

Symbol	Conditions	Values	Units
V <sub>S1</sub>	stabilized 15 V power supply	18	V
V <sub>S2</sub>	unstabilized 24 V power supply	30	V
V <sub>iH</sub>	input signal voltage (high)	15 + 0,3	V
dv/dt	secondary to primary side	75	kV/μs
V <sub>isollO</sub>	input / output (AC, r.m.s., 2s )	2500	Vac
V <sub>isol12</sub>	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac
f <sub>max</sub>	switching frequency	15	kHz
T <sub>op</sub> (T <sub>stg</sub> )	operating / storage temperature	- 25 + 85	°C

Characteristics (T <sub>a</sub> =					= 25 °C)
Symbol	Conditions	min.	typ.	max.	Units
V <sub>S1</sub>	supply voltage stabilized	14,4	15	15,6	V
V <sub>S2</sub>	supply voltage non stabilized	20	24	30	V
I <sub>S1</sub>	V <sub>S1</sub> = 15 V	290+470	290+470*f/f <sub>max</sub> +1,3*(I <sub>AC</sub> /A)		mA
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	220+320	220+320*f/f <sub>max</sub> +1,0*(I <sub>AC</sub> /A)		
V <sub>iT+</sub>	input threshold voltage (High)	11,2			V
V <sub>iT-</sub>	input threshold voltage (Low)			5,4	V
R <sub>IN</sub>	input resistance		10		kΩ
t <sub>d(on)IO</sub>	input-output turn-on propagation time		1,1		μs
t <sub>d(off)IO</sub>	input-output turn-off propagation time		1,4		μs
t <sub>pERRRESET</sub>	error memory reset time	9			μs
t <sub>TD</sub>	top / bottom switch : interlock time		3,3		μs
I <sub>analogOUT</sub>	8 V corresponds to max. current of 15 V supply voltage		1322		A
I <sub>Vs1outmax</sub>	(available when supplied with 24 V)			50	mA
I <sub>A0max</sub>	output current at pin 12/14			5	mA
V <sub>0I</sub>	logic low output voltage			0,6	V
V <sub>0H</sub>	logic high output voltage			30	V
ITRIPSC	over current trip level (I <sub>analog OUT</sub> = 10 V)		1652		Α
I <sub>TRIPLG</sub>	ground fault protection				А
T <sub>tp</sub>	over temperature protection	110		120	°C
UDCTRIP	trip level of U <sub>DC</sub> -protection	400			V
	( U <sub>analog OUT</sub> = 9 V); (option)				

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